

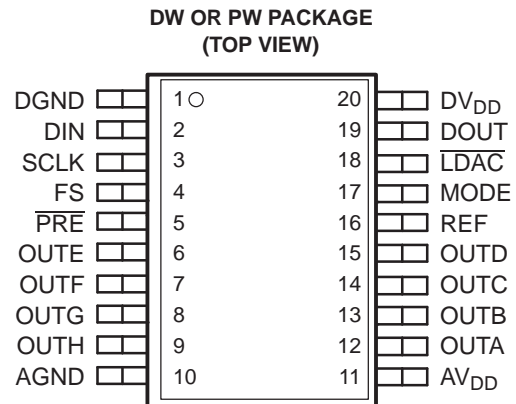
8-CHANNEL, 12-/10-/8-BIT, 2.7-V TO 5.5-V LOW POWER DIGITAL-TO-ANALOG CONVERTER WITH POWER DOWN

FEATURES

- Eight Voltage Output DACs in One Package
 - TLV5610 . . . 12-Bit
 - TLV5608 . . . 10-Bit
 - TLV5629 . . . 8-Bit
- Programmable Settling Time vs Power Consumption
 - 1 μ s In Fast Mode
 - 3 μ s In Slow Mode
- Compatible With TMS320 and SPI™ Serial Ports
- Monotonic Over Temperature
- Low Power Consumption:
 - 18 mW In Slow Mode at 3-V
 - 48 mW In Fast Mode at 3-V
- Reference Input Buffers
- Power-Down Mode
- Buffered, High Impedance Reference Inputs
- Data Output for Daisy-Chaining

APPLICATIONS

- Digital Servo Control Loops
- Digital Offset and Gain Adjustment
- Industrial Process Control
- Machine and Motion Control Devices
- Mass Storage Devices



DESCRIPTION

The TLV5610, TLV5608, and TLV5629 are pin-compatible, eight-channel, 12-/10-/8-bit voltage output DACs each with a flexible serial interface. The serial interface allows glueless interface to TMS320 and SPI, QSPI, and Microwire serial ports. It is programmed with a 16-bit serial string containing 4 control and 12 data bits.

Additional features are a power-down mode, an LDAC input for simultaneous update of all eight DAC outputs, and a data output which can be used to cascade multiple devices.

The resistor string output voltage is buffered by a rail-to-rail output amplifier with a programmable settling time to allow the designer to optimize speed vs power dissipation. The buffered, high-impedance reference input can be connected to the supply voltage.

Implemented with a CMOS process, the DACs are designed for single-supply operation from 2.7 V to 5.5 V, and can operate on two separate analog and digital power supplies. The devices are available in 20-pin SOIC and TSSOP packages.

AVAILABLE OPTIONS

T _A	PACKAGE		
	SMALL OUTLINE (DW)	TSSOP (PW)	RESOLUTION
-40°C to 85°C	TLV5610IDW	TLV5610IPW	12
	TLV5608IDW	TLV5608IPW	10
	TLV5629IDW	TLV5629IPW	8



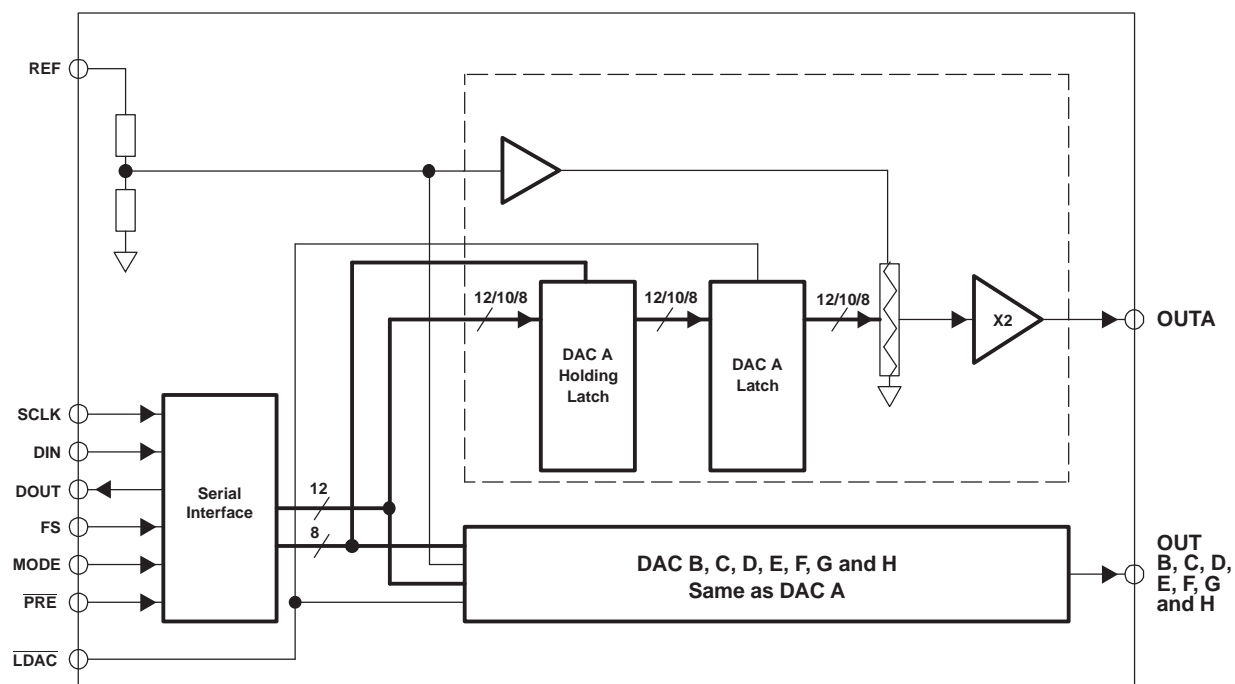
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SPI is a trademark of Motorola, Inc.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

FUNCTIONAL BLOCK DIAGRAM



Terminal Functions

TERMINAL		I/O	DESCRIPTION
NAME	NO.		
AGND	10	I	Analog ground
AV _{DD}	11	I	Analog power supply
DGND	1	I	Digital ground
DIN	2	I	Digital serial data input
DOUT	19	O	Digital serial data output
DV _{DD}	20	I	Digital power supply
FS	4	I	Frame sync input
$\overline{\text{LDAC}}$	18	I	Load DAC. The DAC outputs are only updated, if this signal is low. It is an asynchronous input.
MODE	17	I	DSP/ μ C mode pin. High = μ C mode, NC = DSP mode.
$\overline{\text{PRE}}$	5	I	Preset input
REF	16	I	Voltage reference input
SCLK	3	I	Serial clock input
OUTA-OUTH	6-9, 12-15	O	DAC outputs A, B, C, D, E, F, G and H

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	UNIT
Supply voltage (AV _{DD} , DV _{DD} to GND)	7 V
Reference input voltage	- 0.3 V to AV _{DD} + 0.3 V
Digital input voltage range	- 0.3 V to DV _{DD} + 0.3 V
Operating free-air temperature range, T _A	-40°C to 85°C
Storage temperature range, T _{stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
Supply voltage, AV _{DD} , DV _{DD}	5-V operation	4.5	5	5.5	V
	3-V operation	2.7	3	3.3	V
High-level digital input voltage, V _{IH}	DV _{DD} = 2.7 V	2			V
	DV _{DD} = 5.5 V	2.4			
Low-level digital input voltage, V _{IL}	DV _{DD} = 2.7 V			0.6	V
	DV _{DD} = 5.5 V			1	
Reference voltage, V _{ref}	AV _{DD} = 5 V	GND	4.096	AV _{DD}	V
	AV _{DD} = 3 V	GND	2.048	AV _{DD}	V
Load resistance, R _L		2			kΩ
Load capacitance, C _L				100	pF
Clock frequency, f _{CLK}				30	MHz
Operating free-air temperature, T _A		-40		85	°C

ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range, supply voltages, and reference voltages (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY						
I _{DD}	Power supply current	Fast	No load, V _{ref} = 4.096 V, See ⁽¹⁾ All inputs = DV _{DD} or GND		16	mA
		Slow			6	
	Power down supply current			0.1		μA
POR	Power on threshold			2		V
PSRR	Power supply rejection ratio	Full scale, See ⁽²⁾		-60		dB

- (1) I_{DD} is measured while continuously writing code 2048 to the DAC. For V_{IH} < DV_{DD} - 0.7 V and V_{IL} > 0.7 V, supply current increases.
(2) Power supply rejection ratio at full scale is measured by varying AV_{DD} and is given by:
PSRR = 20 log [(E_G(AV_{DD}max) - E_G(AV_{DD}min))/V_{DD}max]

ELECTRICAL CHARACTERISTICS (continued)

over recommended operating free-air temperature range, supply voltages, and reference voltages (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
STATIC DAC SPECIFICATIONS							
Resolution	TLV5610			12		Bits	
	TLV5608			10			
	TLV5629			8			
Integral nonlinearity (INL)	TLV5610	V _{ref} = 2 V, 4V	Code 40 to 4095	±2	±6	LSB	
	TLV5608		Code 20 to 1023	±0.5	±2		
	TLV5629		Code 6 to 255	±0.3	±1		
Differential nonlinearity (DNL)	TLV5610	V _{ref} = 2 V, 4V	Code 40 to 4095	±0.5	±1	LSB	
	TLV5608		Code 20 to 1023	±0.1	±1		
	TLV5629		Code 6 to 255	±0.1	±1		
E _{ZS}	Zero-scale error (offset error at zero scale)				±30	mV	
E _{ZS} TC	Zero-scale-error temperature coefficient				30	μV/°C	
E _G	Gain error				±0.6	% of FS voltage	
E _G TC	Gain error temperature coefficient				10	ppm/°C	
OUTPUT SPECIFICATIONS							
V _O	Voltage output range		R _L = 10 kΩ	0	AV _{DD} - 0.4	V	
Output load regulation accuracy			R _L = 2 kΩ vs 10 kΩ	±0.3		% of FS voltage	
REFERENCE INPUT							
V _I	Reference input voltage			0	AV _{DD}	V	
R _I	Reference input resistance			100		kΩ	
C _I	Reference input capacitance			5		pF	
Reference input bandwidth	Fast	V _{ref} = 0.4 V _{pp} + 2.048 Vdc, Input code = 0x800		2.2		MHz	
	Slow	V _{ref} = 2 V _{pp} at 1 kHz + 2.048 Vdc, See ⁽³⁾		1.9			
Reference feedthrough				-84		dB	
DIGITAL INPUT							
I _{IH}	High-level digital input current		V _I = V _{DD}	1		μA	
I _{IL}	Low-level digital input current		V _I = 0 V	-1		μA	
C _I	Input capacitance			8		pF	
DIGITAL OUTPUT							
V _{OH}	High-level digital output voltage		R _L = 10 kΩ	2.6		V	
V _{OL}	Low-level digital output voltage		R _L = 10 kΩ	0.4		V	
Output voltage rise time			R _L = 10 kΩ, C _L = 20 pF, Includes propagation delay	7 20		ns	

(3) Reference feedthrough is measured at the DAC output with an input code = 0x000.

ELECTRICAL CHARACTERISTICS (continued)

over recommended operating free-air temperature range, supply voltages, and reference voltages (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
ANALOG OUTPUT DYNAMIC PERFORMANCE							
t _{s(FS)}	Output settling time (full scale)	Fast	R _L = 10 kΩ, C _L = 100 pF, See ⁽⁴⁾	1		3	μs
		Slow		3		7	
t _{s(CC)}	Output settling time, code to code	Fast	R _L = 10 kΩ, C _L = 100 pF, See ⁽⁵⁾	0.5		1	μs
		Slow		1		2	
SR	Slew rate	Fast	R _L = 10 kΩ, C _L = 100 pF, See ⁽⁶⁾	4	10		V/μs
		Slow		1	3		
Glitch energy			See ⁽⁷⁾	4		nV-s	
Channel crosstalk			10 kHz sine, 4 V _{PP}	-90		dB	

- (4) Settling time is the time for the output signal to remain within +0.5 LSB of the final measured value for a digital input code change of 0x80 to 0xFFF and 0xFFF to 0x80, respectively. Assured by design; not tested.
- (5) Settling time is the time for the output signal to remain within +0.5 LSB of the final measured value for a digital input code change of one count. The max time applies to code changes near zero scale or full scale. Assured by design; not tested.
- (6) Slew rate determines the time it takes for a change of the DAC output from 10% to 90% full scale voltage.
- (7) Code transition: TLV5610 - 0x7FF to 0x800, TLV5608 - 0x7FC to 0x800, TLV5629 - 0x7F0 to 0x800

TIMING REQUIREMENTS

DIGITAL INPUTS					
		MIN	NOM	MAX	UNIT
t _{su} (FS-CK)	Setup time, FS low before next negative SCLK edge	8			ns
t _{su} (C16-FS)	Setup time, 16 th negative edge after FS low on which bit D0 is sampled before rising edge of FS. μC mode only	10			ns
t _{su} (FS-C17)	μC mode, setup time, FS high before 17 th negative edge of SCLK.	10			ns
t _{su} (CK-FS)	DSP mode, setup time, SLCK low before FS low.	5			ns
t _{wL} (LDAC)	$\overline{\text{LDAC}}$ duration low	10			ns
t _{wH}	SCLK pulse duration high	16			ns
t _{wL}	SCLK pulse duration low	16			ns
t _{su} (D)	Setup time, data ready before SCLK falling edge	8			ns
t _h (D)	Hold time, data held valid after SCLK falling edge	5			ns
t _{wH} (FS)	FS duration high	10			ns
t _{wL} (FS)	FS duration low	10			ns
t _s	Settling time	See AC specs			

PARAMETER MEASUREMENT INFORMATION

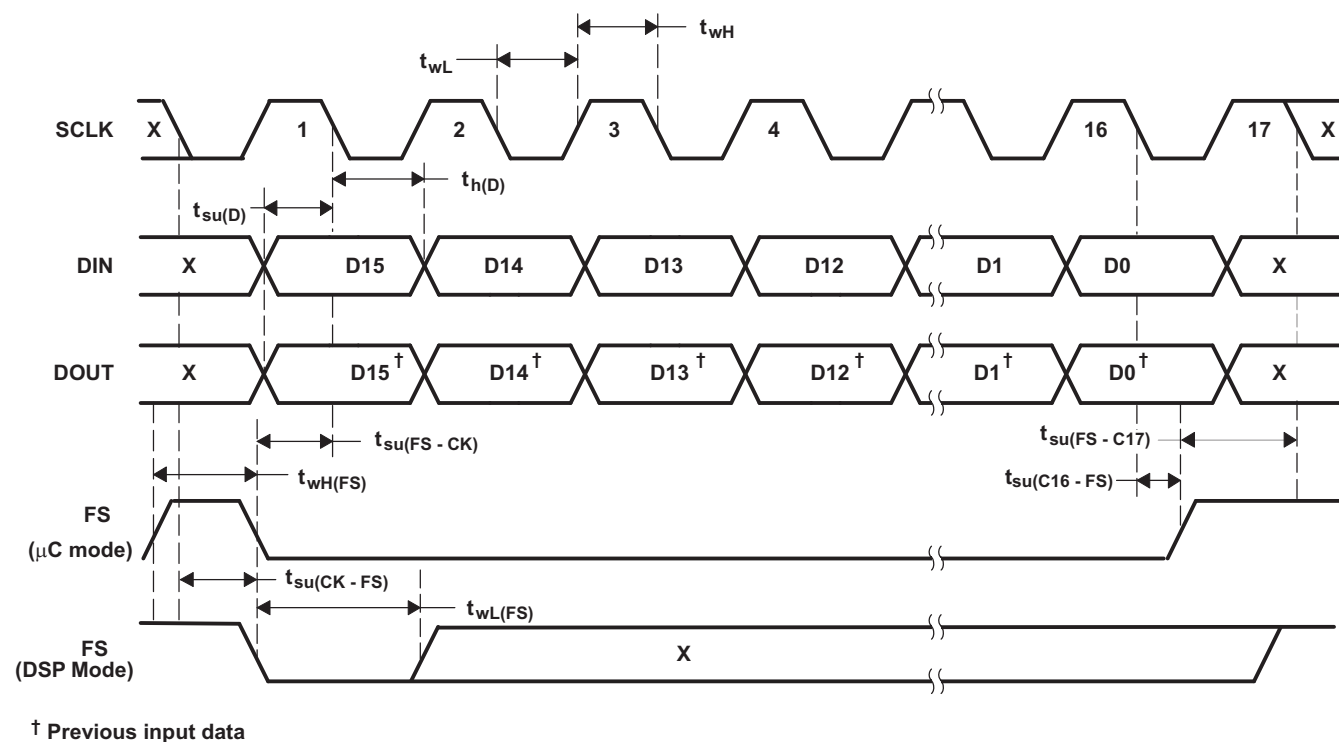


Figure 1. Serial Interface Timing

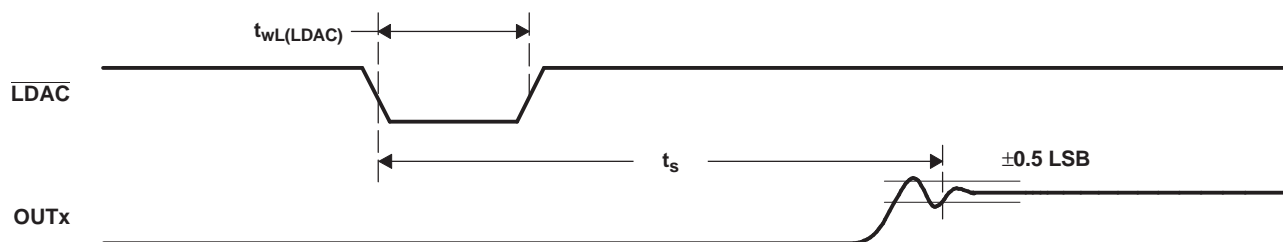


Figure 2. Output Timing

TYPICAL CHARACTERISTICS

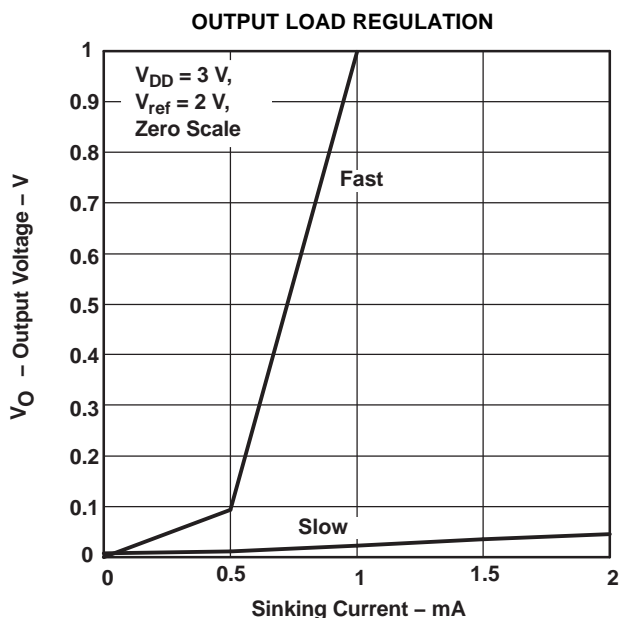


Figure 3.

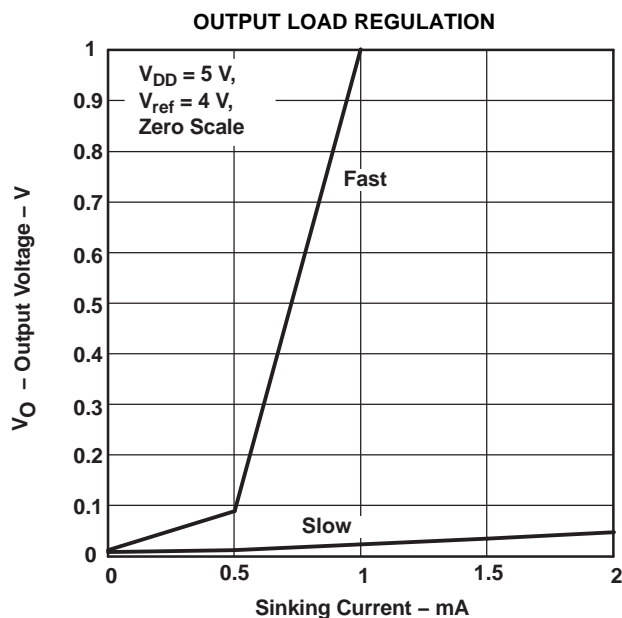


Figure 4.

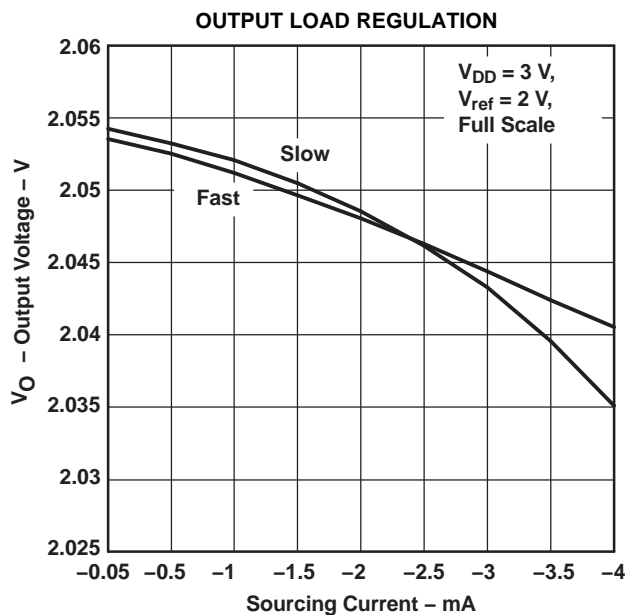


Figure 5.

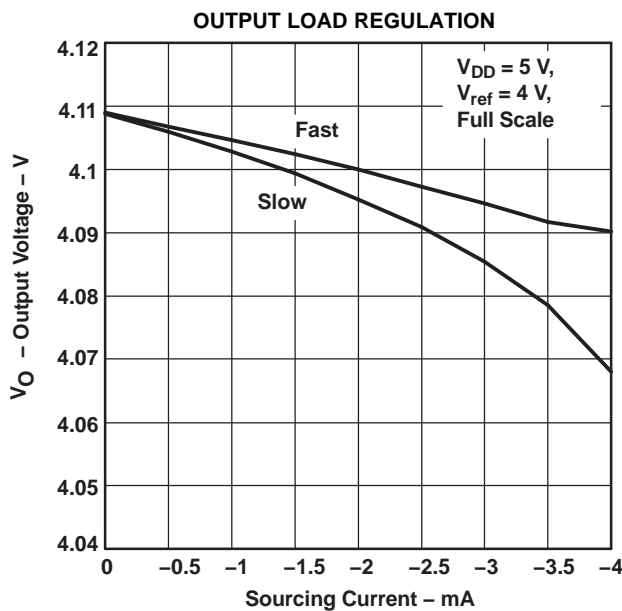


Figure 6.

TYPICAL CHARACTERISTICS (continued)

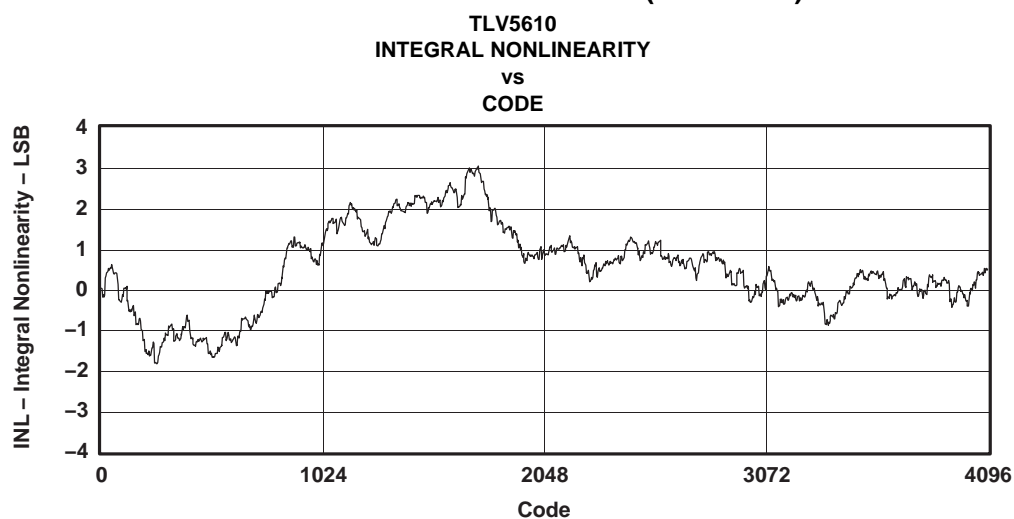


Figure 7.

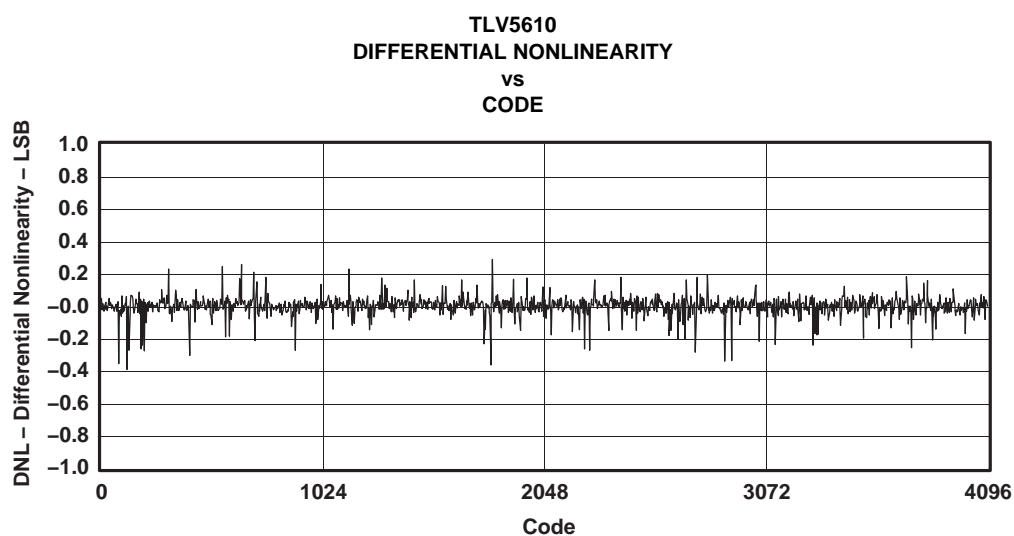


Figure 8.

TYPICAL CHARACTERISTICS (continued)

**TLV5608
INTEGRAL NONLINEARITY
vs
CODE**

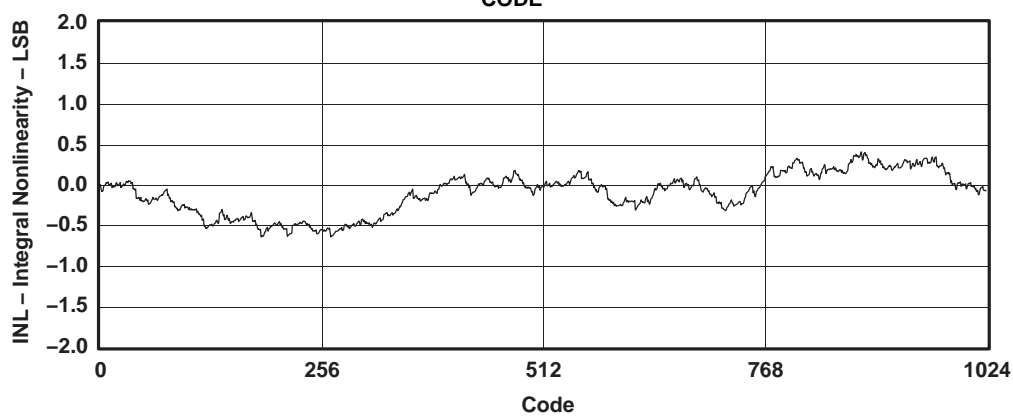


Figure 9.

**TLV5608
DIFFERENTIAL NONLINEARITY
vs
CODE**

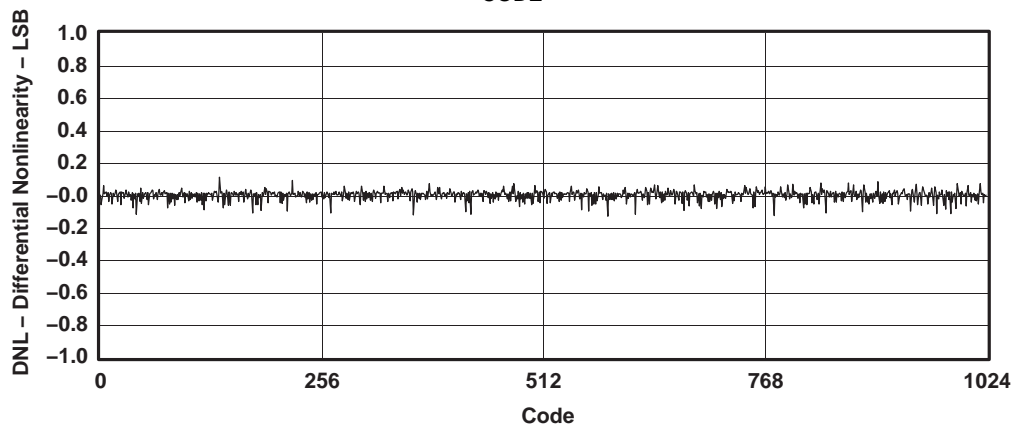
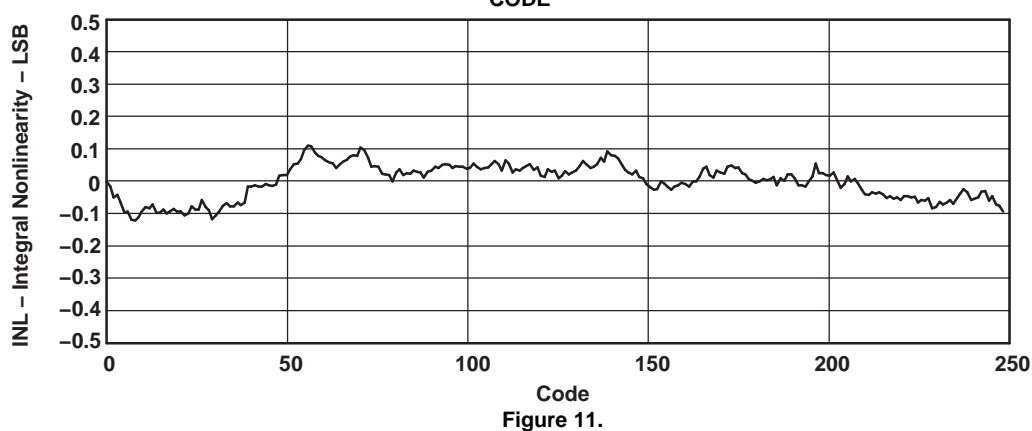


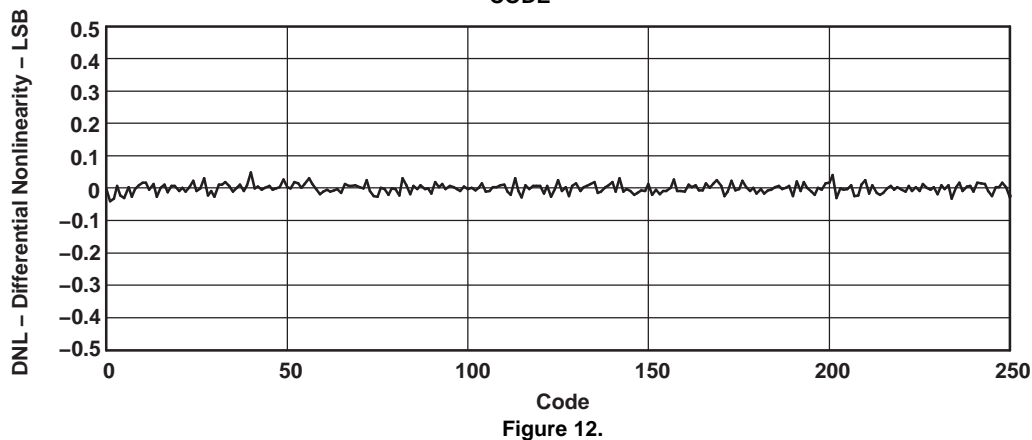
Figure 10.

TYPICAL CHARACTERISTICS (continued)

TLV5629
INTEGRAL NONLINEARITY
vs
CODE



TLV5629
DIFFERENTIAL NONLINEARITY
vs
CODE



APPLICATION INFORMATION

GENERAL FUNCTION

The TLV5610, TLV5608, and TLV5629 are 8-channel, 12-bit, single-supply DACs, based on a resistor string architecture. They consist of a serial interface, a speed and power-down control logic, a reference input buffer, a resistor string, and a rail-to-rail output buffer.

The output voltage (full scale determined by external reference) for each channel is given by:

$$V_{REF} \frac{CODE}{0x1000} [V] \quad (1)$$

where REF is the reference voltage and CODE is the digital input value. The input range is 0x000 to 0xFFF for the TLV5610, 0x000 to 0xFFC for the TLV5608, and 0x000 to 0xFF0 for the TLV5629.

POWER ON RESET (POR)

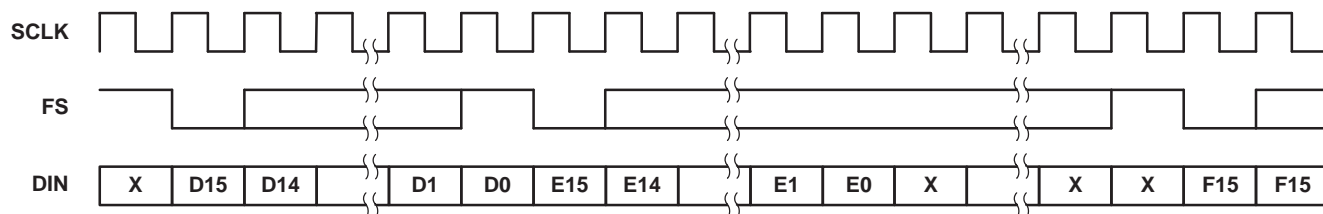
The built-in power-on-reset circuit controls the output voltage after power up. On power up, all latches including the preset register are set to zero, but the DAC outputs are only set to zero if the LDAC is low. The DAC outputs may have a small offset error produced by the output buffer. The registers remains at zero until a valid write sequence is made to the DAC, changing the DAC register data. This is useful in applications where it is important to know the state of the outputs of the DAC after power up. All digital inputs must be logic low until the digital and analog supplies are applied. Any logic high voltages applied to the logic input pins when power is not applied to AV_{DD} and DV_{DD}, may power the device logic circuit through the overvoltage protection diode causing an undesired operation. When separate analog (AV_{DD}) and digital (DV_{DD}) supplies are used, AV_{DD} must come up first before DV_{DD}, to ensure that the power-on-reset circuit operates correctly.

SERIAL INTERFACE

A falling edge of FS starts shifting the data on DIN starting with the MSB to the internal register on the falling edges of SCLK. After 16 bits have been transferred, the content of the shift register is moved to one of the DAC holding registers, depending on the address bits within the data word. A logic 0 on the LDAC pin is required to transfer the content of the DAC holding register to the DAC latch and to update the DAC outputs. LDAC is an asynchronous input. It can be held low if a simultaneous update of all eight channels is not needed.

For daisy-chaining, DOUT provides the data sampled on DIN with a delay of 16 clock cycles.

DSP Mode:



μC Mode:

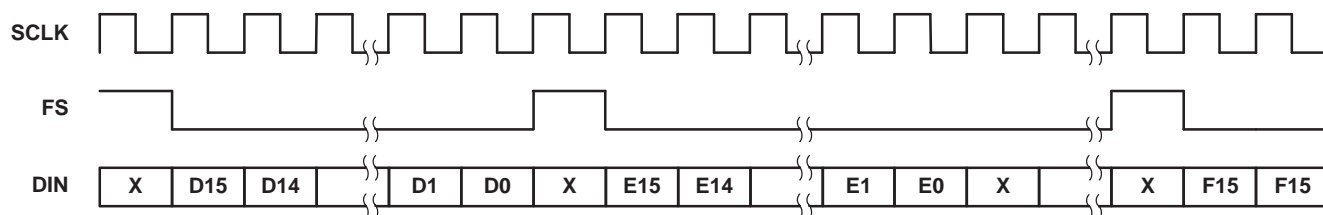


Figure 13. Data Sampled on DIN

Difference between DSP mode (MODE = N.C. or 0) and μ C (MODE = 1) mode:

- In μ C mode, FS needs to be held low until all 16 data bits have been transferred. If FS is driven high before the 16th falling clock edge, the data transfer is cancelled. The DAC is updated after a rising edge on FS.
- In DSP mode, FS needs to stay low for 20 ns and can go high before the 16th falling clock edge.
- In DSP mode there needs to be one falling SCLK edge before FS goes low to start the write (DIN) cycle. This extra falling SCLK edge has to happen at least 5 ns before FS goes low, $t_{su(CK-FS)} \geq 5$ ns.
- In μ C mode, the extra falling SCLK edge is not necessary. However, if it does happen, the extra negative SCLK edge is not allowed to occur within 10 ns after FS goes HIGH to finish the WRITE cycle ($t_{su(FS-C17)}$).

SERIAL CLOCK FREQUENCY AND UPDATE RATE

The maximum serial clock frequency is given by:

$$f_{sclkmax} = \frac{1}{t_{whmin} + t_{wlmin}} = 30 \text{ MHz} \quad (2)$$

The maximum update rate is:

$$f_{updatemax} = \frac{1}{16(t_{whmin} + t_{wlmin})} = 1.95 \text{ MHz} \quad (3)$$

Note, that the maximum update rate is just a theoretical value for the serial interface, as the settling time of the DAC has to be considered also.

DATA FORMAT

The 16-bit data word consists of two parts:

- Address bits (D15D12)
- Data bits (D11D0)

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
A3	A2	A1	A0	DATA											

Register Map

A3	A2	A1	A0	FUNCTION
0	0	0	0	DAC A
0	0	0	1	DAC B
0	0	1	0	DAC C
0	0	1	1	DAC D
0	1	0	0	DAC E
0	1	0	1	DAC F
0	1	1	0	DAC G
0	1	1	1	DAC H
1	0	0	0	CTRL0
1	0	0	1	CTRL1
1	0	1	0	Preset
1	0	1	1	Reserved
1	1	0	0	DAC A and \overline{B}
1	1	0	1	DAC C and \overline{D}
1	1	1	0	DAC E and \overline{F}
1	1	1	1	DAC G and \overline{H}

DAC A-H AND TWO-CHANNEL REGISTERS

Writing to DAC A-H sets the output voltage of channel A-H. It is possible to automatically generate the complement of one channel by writing to one of the four two-channel registers (DAC A and B etc.).

The TLV5610 decodes all 12 data bits. The TLV5608 decodes D11 to D2 (D1 and D0 are ignored). The TLV5629 decodes D11 to D4 (D3 to D0 are ignored).

PRESET

The outputs of the DAC channels can be driven simultaneously to a predefined value stored in the preset register by driving the $\overline{\text{PRE}}$ input pin low and asserting the $\overline{\text{LDAC}}$ input pin. The preset register is cleared (set to zero) by the POR circuit after power up. Therefore, it must be written with a predefined value before asserting the $\overline{\text{PRE}}$ pin low, unless zero is the desired preset value. The $\overline{\text{PRE}}$ input is asynchronous to the clock.

CTRL0

D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
X	X	X	X	X	X	X	PD	DO	X	X	IM

PD	: Full device power down	0 = normal	1 = power down
DO	: Digital output enable	0 = disable	1 = enable
IM	: Input mode	0 = straight binary	1 = twos complement
X	: Reserved		

If DOUT is enabled, the data input on DIN is output on DOUT with a 16-cycle delay. That makes it possible to daisy-chain multiple DACs on one serial bus.

CTRL1

D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
X	X	X	X	P _{GH}	P _{EF}	P _{CD}	P _{AB}	S _{GH}	S _{EF}	S _{CD}	S _{AB}

P _{XY}	: Power down DAC _{XY}	0 = normal	1 = power down
S _{XY}	: Speed DAC _{XY}	0 = slow	1 = fast
XY	: DAC pair AB, CD, EF, or GH		

In power-down mode, the amplifiers of the selected DAC pair within the device are disabled and the total power consumption of the device is significantly reduced. Power-down mode of a specific DAC pair can be selected by setting the PXY bit within the data word to 1.

There are two settling time modes: fast and slow. Fast mode of a DAC pair is selected by setting S_{XY} to 1 and slow mode is selected by setting S_{XY} to 0.

REFERENCE

The DAC reference can be sourced externally using precision reference circuits. Since the reference input is buffered, it can be connected to the supply voltage.

BUFFERED AMPLIFIER

The DAC outputs are buffered by an amplifier with a gain of two, which are configurable as Class A (fast mode) or Class AB (slow or low-power mode). The output buffers have near rail-to-rail output with short-circuit protection, and can reliably drive a 2-kΩ load with a 100-pF load capacitance.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV5608IDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5608I	Samples
TLV5608IDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5608I	Samples
TLV5608IDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5608I	Samples
TLV5608IPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5608	Samples
TLV5608IPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5608	Samples
TLV5608IPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5608	Samples
TLV5608IPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5608	Samples
TLV5610IDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5610I	Samples
TLV5610IDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5610I	Samples
TLV5610IDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5610I	Samples
TLV5610IPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5610	Samples
TLV5610IPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5610	Samples
TLV5610IPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5610	Samples
TLV5610IPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5610	Samples
TLV5629IDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5629I	Samples
TLV5629IDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5629I	Samples
TLV5629IDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLV5629I	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV5629IPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5629	Samples
TLV5629IPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5629	Samples
TLV5629IPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5629	Samples
TLV5629IPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY5629	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV5608IDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
TLV5608IPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TLV5610IDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
TLV5610IPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TLV5629IDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
TLV5629IPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

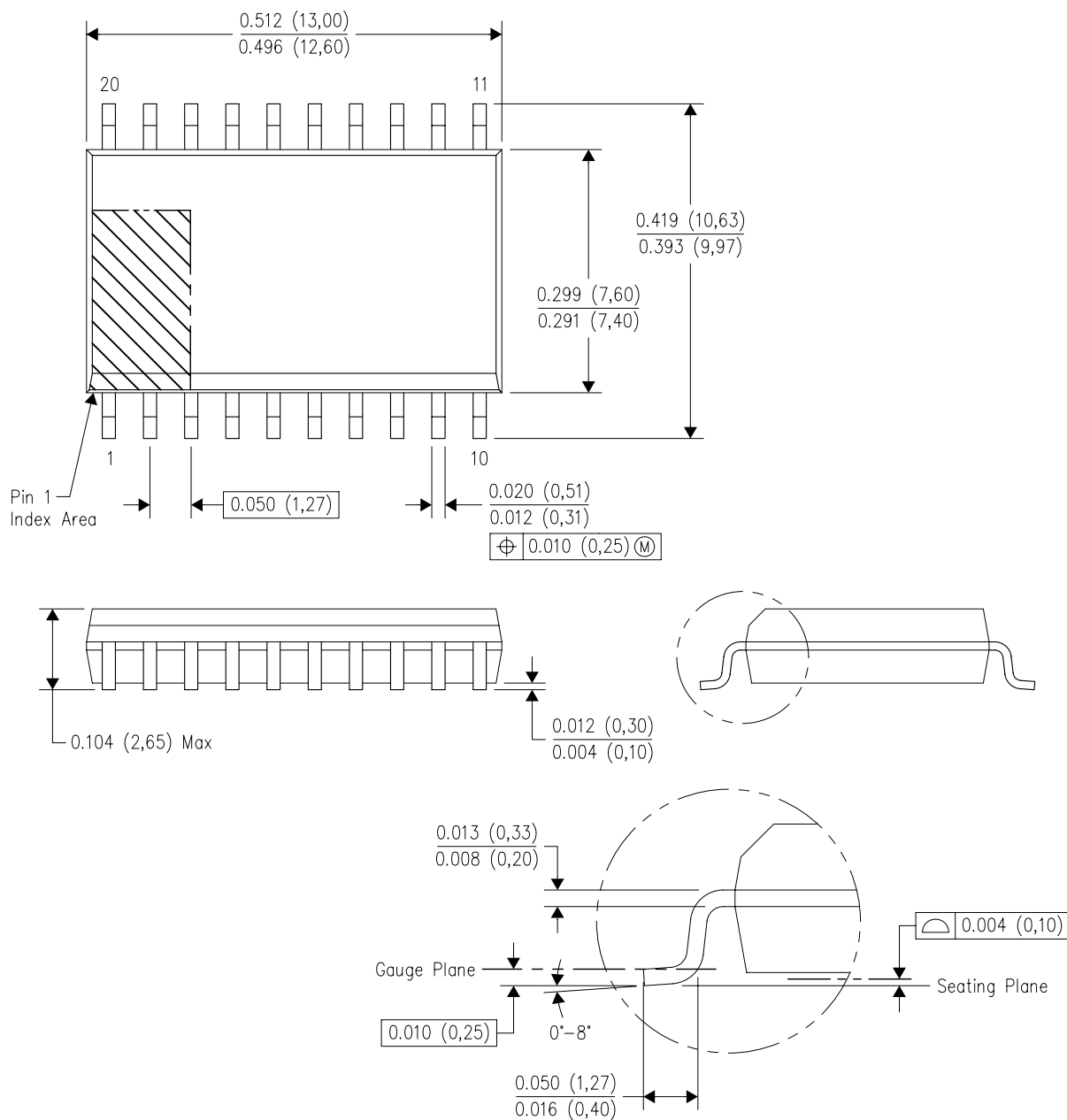


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV5608IDWR	SOIC	DW	20	2000	367.0	367.0	45.0
TLV5608IPWR	TSSOP	PW	20	2000	367.0	367.0	38.0
TLV5610IDWR	SOIC	DW	20	2000	367.0	367.0	45.0
TLV5610IPWR	TSSOP	PW	20	2000	367.0	367.0	38.0
TLV5629IDWR	SOIC	DW	20	2000	367.0	367.0	45.0
TLV5629IPWR	TSSOP	PW	20	2000	367.0	367.0	38.0

DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



4040000-4/G 01/11

- NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
D. Falls within JEDEC MS-013 variation AC.

DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Refer to IPC7351 for alternate board design.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



4040064-5/G 02/11

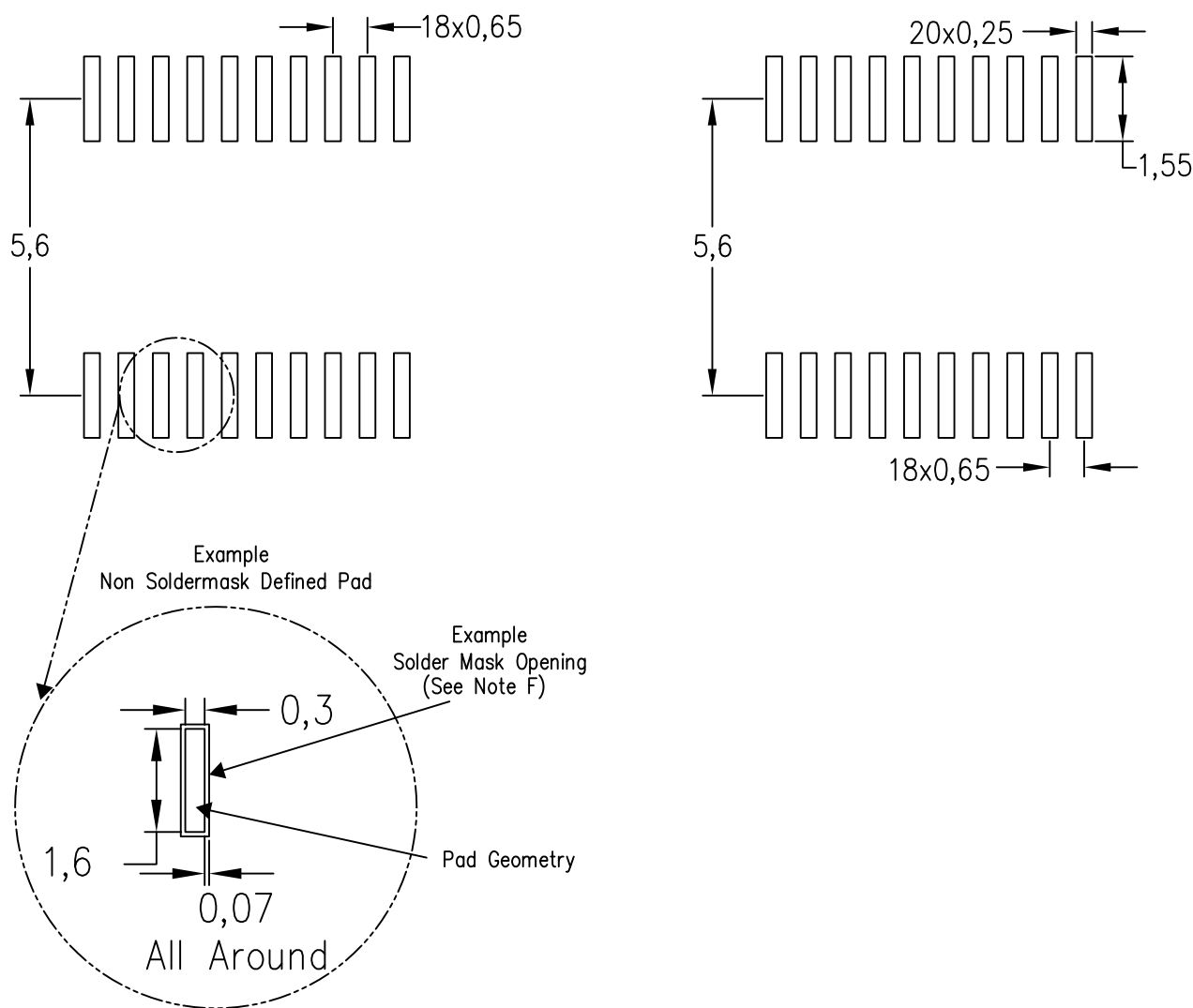
- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE

Example Board Layout

Based on a stencil thickness
of .127mm (.005inch).



4211284-5/F 12/12

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate design.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com